NSN 5961-01-356-1396

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-1396 **Inclosure Material:** Metal **Overall Length:** 0.175 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.352 inches **End Application:** General purpose electronic test equipment gpete, tarawa class lha Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, dc all transistor and 5.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 4.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset all transistor **Special Features:** Weapon system essential; transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No